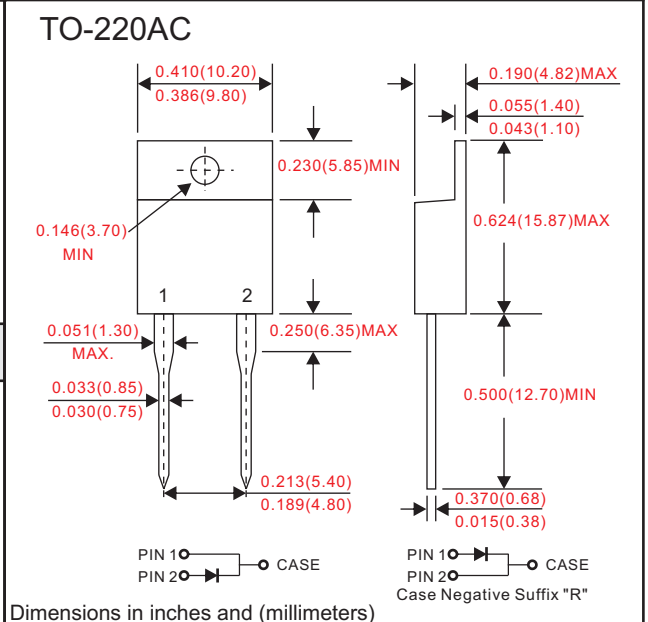


ET8005 THRU ET810

8.0 Amperes Super High Power Super Fast Rectifiers
VOLTAGE : 50 TO 1000Volts

Features	Outline
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- High current capability, low forward voltage drop.
- High surge capability.
- Superfast recovery time for switching mode application.
- Glass passivated chip junction.
- Suffix "G" indicates Halogen free parts, ex. ET8005G.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228



Mechanical data

- Epoxy : UL94-V0 rated flame retardant.
- Case : JEDEC TO-220AC molded plastic body over passivated chip.
- Lead : Axial leads, solderable per MIL-STD-202, Method 208 guaranteed.
- Polarity: Color band denotes cathode end.
- Mounting Position : Any.
- Weight : Approximated 1.86 gram.

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS
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Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbol	ET8005	ET801	ET802	ET804	ET806	ET808	ET810	UNIT	
Making code		ET8005	ET801	ET802	ET804	ET806	ET808	ET810		
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V	
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700		
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000		
Maximum Forward Voltage	V_F	0.95			1.30	1.70			V	
Maximum reverse recovery time(1) @ $T_J = 25^\circ C$	T_{rr}	35			50				ns	
Operating Temperature	T_J	-50 ~ +150								°C

Note : 1. $I_F = 0.5A$, $I_R = 1.0A$, $I_{RR} = 0.25A$

Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current		I_o			8.0	A
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC methode)	I_{FSM}			125	A
Reverse current	$V_R = V_{RRM}$ $T_A = 25^\circ C$	I_R			1.0	uA
	$V_R = V_{RRM}$ $T_A = 125^\circ C$				300	
Typical junction capacitance	f=1MHz and applied 4V DC reverse voltage	C_J		80		pF

ET8005 THRU ET810

8.0 Amperes Super High Power Super Fast Rectifiers
VOLTAGE : 50 TO 1000Volts

Rating and characteristic curves

FIG.1- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

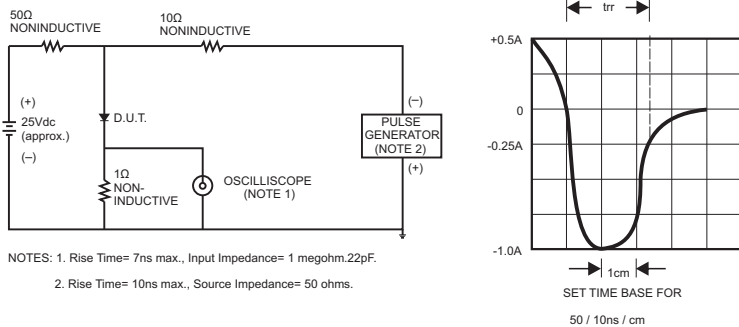


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

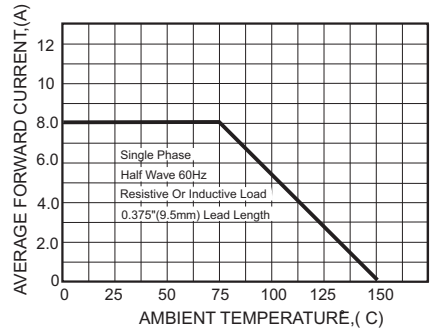


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

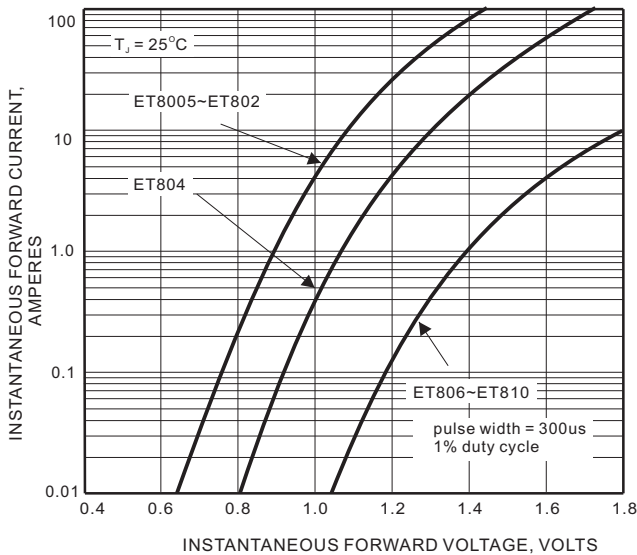


FIG.4-TYPICAL REVERSE CHARACTERISTICS

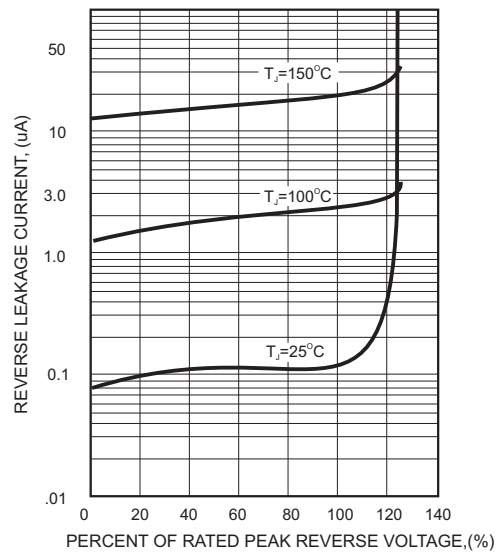


FIG.5-MAXIMUM NON-REPETITIVE

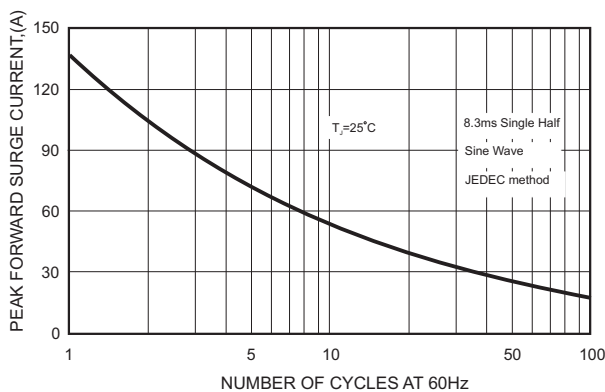


FIG.6-TYPICAL JUNCTION CAPACITANCE

